MAPS Simulation Status

5th October 2006

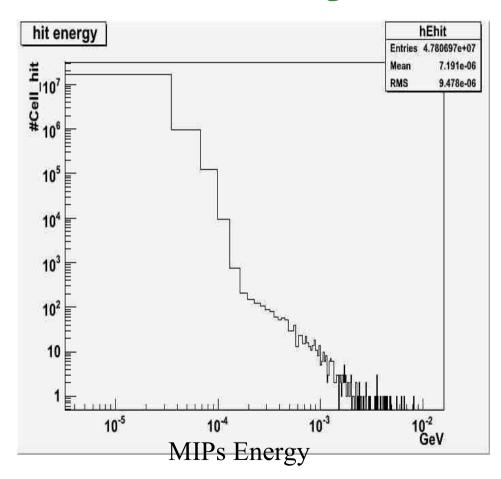
MAPS meeting at Rutherford Appleton Laboratory

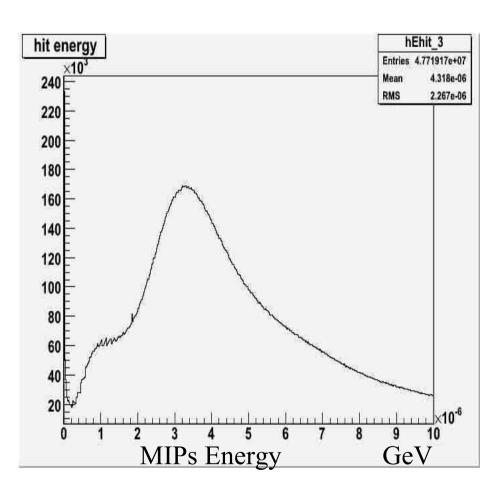
Yoshinari Mikami

University of Birmingham

- Contents
 - Energy deposit distribution
 - 48 contiguous cells hits pattern

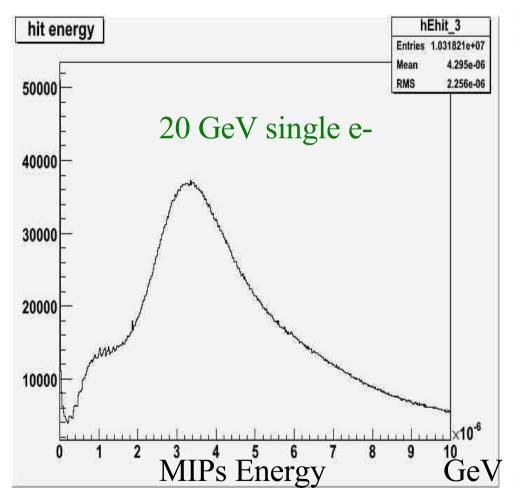
- -15µm Si sensitive thickness
- -50μm x 50μm cell size
- -100 GeV single electron

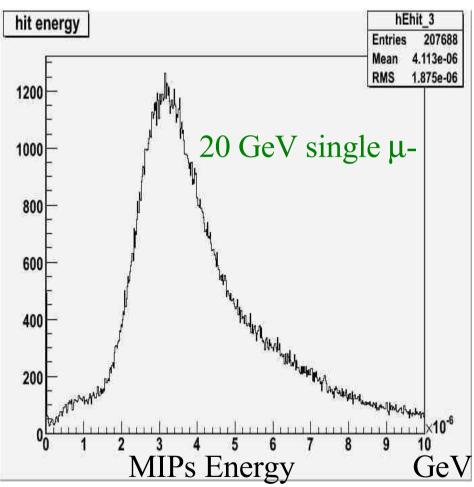


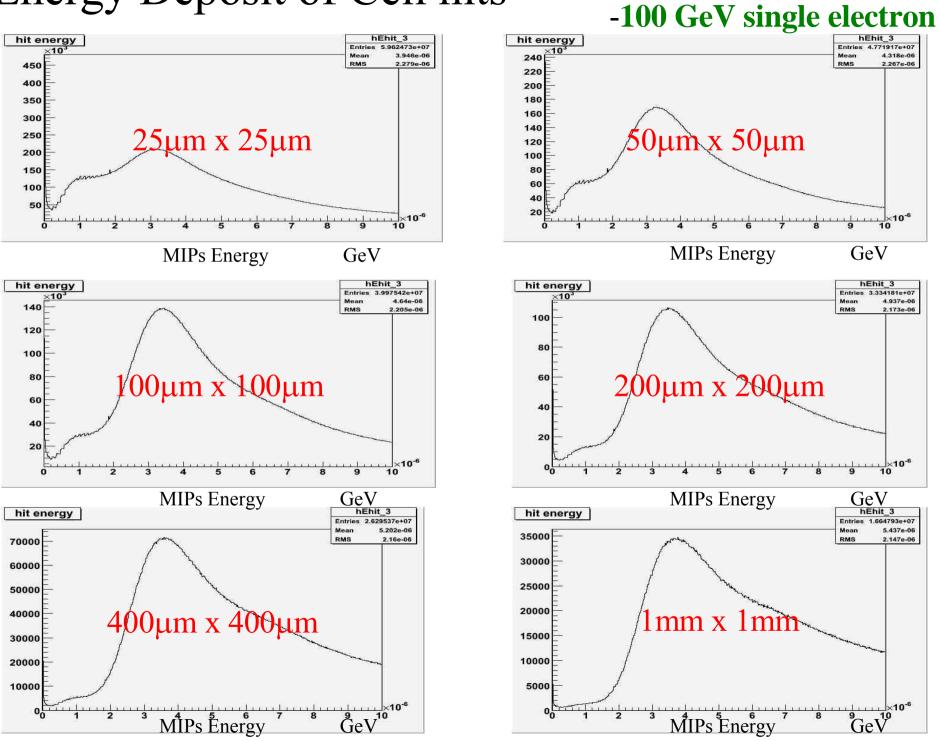


~3.5 KeV MIPs peak

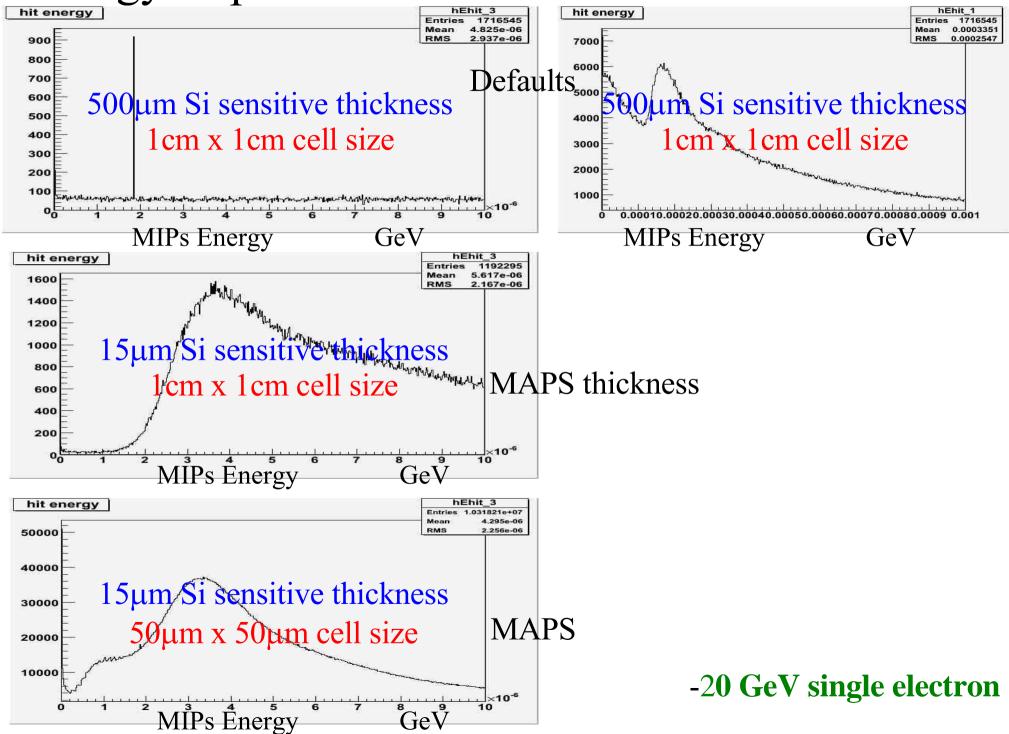
- -15µm Si sensitive thickness
- -50μm x 50μm cell size



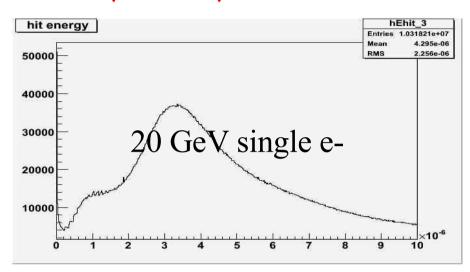


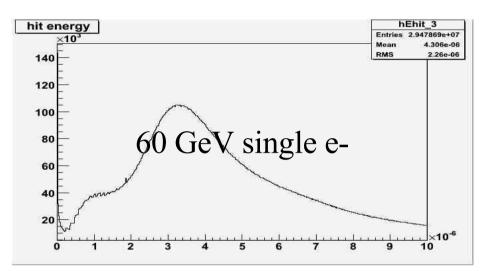


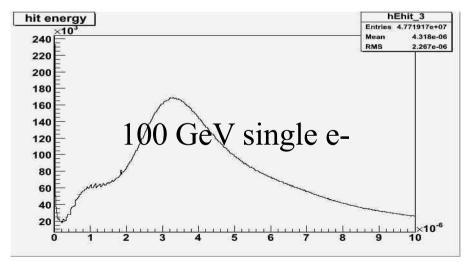
-15µm Si sensitive thickness



- -15µm Si sensitive thickness
- -50μm x 50μm cell size







Mean value dose not depend on incoming electron energies. --->Single MIP in each cell. (Individual MIP can be detected.)

48 contiguous cell hit pattern study (Under study)

CellID0 -Stave CellID1 -Cell z index
-Module -Provision
-Layer -sign
-Cell x index
-Guard-ring zone
-Sign

- After extracting Cell z index from CellID1, contiguous 48 hits are added with requiring the same CellID0.
 - (Double counts are removed.)
 - Code is almost available.
 - → Hopefully, I can show some distributions in next meeting.

Summary of status

- -48 contiguous cell hit pattern is probably available in the next.
- -Individual secondary particle angle study depends on getNMCcontributions() output.
 - <-- I have to ask some expart about this.
- -50um x 50um pixel size seems to be optimized.